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LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT

ATTY. DOCKET NO.: P67201US0 GROUP ART UNIT: 2814
SERIAL NO.: 09/975,963 FILING DATE: October 15, 2001
APPLICANT(S): Wonju CHO, et al. TODAY'S DATE: June 20, 2003

U.S. PATENT DOCUMENTS

*EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	INT'L CLASS	SUB- CLASS	FILING DATE (If Appropriate)
AA						
AB						
AC						

FOREIGN PATENT DOCUMENTS

	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB- CLASS	TRANSLATION (YES) (NO)
<u>LP</u>	AD 08-227997	09/03/96	Japan	H01L	29/78	X
<u> </u>	AE 07-099311	04/11/95	Japan	H01L	29/78	X
<u> </u>	AF 2000-174269	06/23/00	Japan	H01L	29/78	X
<u>↓</u>	AG 10-189764	07/21/98	Japan	H01L	21/8238	X

OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)

AH _____

EXAMINER

DATE CONSIDERED

Long Pham4/18/04

* EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant(s).

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ATTY. DOCKET NO.: P67201US0 GROUP ART UNIT: Not Yet Assigned
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*EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	INT'L CLASS	SUB- CLASS	FILING DATE (If Appropriate)
<u>LP</u>	AA 5,365,097	11/15/94	Kenney	H01L	29/68	10/05/92
<u>LP</u>	AB 5,382,816	01/17/95	Mitsui	H01L	29/10	05/28/93
	AC					

FOREIGN PATENT DOCUMENTS

	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB- CLASS	TRANSLATION (YES) (NO)
	AD					1
	AE					1

OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)

LP AF Hergenrother, et al.; The Vertical Replacement-Gate (VRG) MOSFET: A 50-nm....; 1999 IEEE; p.99-75 - 99-78.

LP AG Hergenrother, et al.; The Vertical Replacement-Gate (VRG) MOSFET With; 2000 Extended Abstract of; p. 220-221.

AH

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